PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of:

Keisuke TSUKAMOTO et al.

Appln. No.:

Filed: HEREWITH

For: A SEMICONDUCTOR INTEGRATED CIRCUIT DEVICE AND A

METHOD OF MANUFACTURING THE SAME

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Applicants wish to make of record the documents cited in prior Application No. 10/196,166 filed July 17, 2002, whether cited by Applicants or by the Patent Office. documents are listed on the attached Form PTO-1449.

Respectfully submitted,

MWS: lmb

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Mitchell W.

Req. No. 31,568

February 26, 2004

FORM PTO-1449					Atty. Docket	No.	App	Appln. No.	
					XA-9721A				
LIST OF DOCUMENTS CITED BY APPLICANT									
					Applicant				
					Keisuke TSUKAMOTO et al.				
					Filing Date		Gro	Group	
					HEREWITH				
			U.S.	PATENT DO	CUMENTS	. , .			
Examiner Initial		Document Number	Date	Name		Class	Sub- class	Filing Date	
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	AB								
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Examiner Initial		Document Number	Date	Cou	ntry	Class	Sub- class	Translation	
	AJ								
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	AL								
	AM								
	AN		·						
	AO								
OTHER (including author, title, date, pertinent pages, etc.)									
	ΑP	Kim et al., "A Novel 4.6F ² NOR Cell Technology With Lightly Doped Source (LDS) Junction For High Density Flash Memories," IEDM (International Electron Devices Meeting), 1998, pp. 979-982.							
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Include copy of this form with next communication to Applicant.									